



Image may be representation. See specifications for product details.

EDB5432BEBH-1DAAT-F-D

Part Number:	EDB5432BEBH-1DAAT-F-D
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 512M PARALLEL 134VFBGA
Datasheets:	 EDB5432BEBH-1DAAT-F-D.pdf
RoHs Status	 Lead free / RoHS Compliant
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

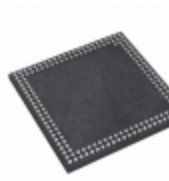
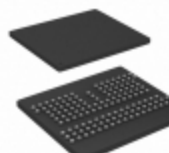
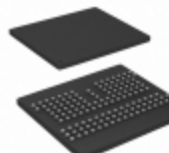
Specifications of EDB5432BEBH-1DAAT-F-D

PART NUMBER	EDB5432BEBH-1DAAT-F-D
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 512M PARALLEL 134VFBGA
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DATA SHEET	 EDB5432BEBH-1DAAT-F-D.pdf
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	1.14 V ~ 1.95 V
TECHNOLOGY	SDRAM - Mobile LPDDR2
SUPPLIER DEVICE PACKAGE	134-VFBGA (10x11.5)
SERIES	-
PACKAGING	Tray
PACKAGE / CASE	134-VFBGA
OPERATING TEMPERATURE	-40°C ~ 105°C (TC)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	512Mb (16M x 32)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - Mobile LPDDR2 Memory IC 512Mb (16M x 32) Parallel 533MHz 134-VFBGA (10x11.5)
CLOCK FREQUENCY	533MHz

Related Tags

Micron Technology EDB5432BEBH-1DAAT-F-D	EDB5432BEBH-1DAAT-F-D Distributor	EDB5432BEBH-1DAAT-F-D Supplier
EDB5432BEBH-1DAAT-F-D Price	EDB5432BEBH-1DAAT-F-D Pictures	EDB5432BEBH-1DAAT-F-D Image
EDB5432BEBH-1DAAT-F-D PDF Datasheet	EDB5432BEBH-1DAAT-F-D Download Datasheet	EDB5432BEBH-1DAAT-F-D Datasheet
EDB5432BEBH-1DAAT-F-D Stock	Buy EDB5432BEBH-1DAAT-F-D	Buy Micron Technology EDB5432BEBH-1DAAT-F-D
Micron Technology EDB5432BEBH-1DAAT-F-D	Micron Technology Supplier	Micron Technology Distributor
Micron Technology EDB5432BEBH-1DAAT-F-D	Micron Technology Inc. EDB5432BEBH-1DAAT-F-D	

Related Products

 EDB5432BEPA-1DAAT-F-D Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 168WFBGA In stock: Out stock RFQ	 EDB4432BBBJ-1DAUT-F-D Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 533MHZ In stock: Out stock RFQ
 EDB4432BBPA-1D-F-D Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 168FBGA In stock: Out stock RFQ	 EDB4432BBBJ-1DAUT-F-R TR Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 533MHZ In stock: Out stock RFQ
 EDB5432BEBH-1DAUT-F-D Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 134VFBGA In stock: Out stock RFQ	 EDB4432BBPE-1D-F-D Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 533MHZ In stock: Out stock RFQ
 EDB5432BEBH-1DIT-F-R TR Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 134VFBGA In stock: Out stock RFQ	 EDB4432BBPA-1D-F-R TR Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 168FBGA In stock: Out stock RFQ
 EDB5432BEBH-1DIT-F-D Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 134VFBGA In stock: Out stock RFQ	 EDB5432BEBH-1DAUT-F-R TR Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 134VFBGA In stock: Out stock RFQ
 EDB5432BEBH-1DAAT-F-R TR Manufacturers: Micron Technology Description: IC DRAM 512M PARALLEL 134VFBGA In stock: Out stock RFQ	 EDB4432BBBJ-1DAIT-F-R TR Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 134FBGA In stock: Out stock RFQ